

Supporting Information

The Surface Charge Induced High Activity of Oxygen Reduction Reaction on the PdTe₂ Bilayer

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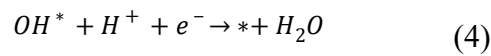
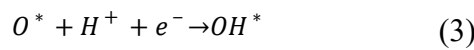
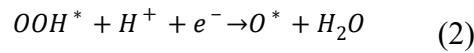
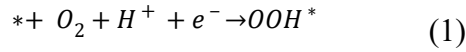
Computational Details

Density functional theory calculations are carried out using the Vienna *ab initio* simulation package (VASP) interfaced with Atomic Simulation Environment (ASE).¹ The interaction between ionic cores and valence electrons is described using the projector augmented wave (PAW) method.² The energy cutoff for the plane-wave basis is 400 eV. The PBE⁴ and revised PBE⁵ functionals combined with DFT-D2⁶ and DFT-D3^{7,8} dispersion corrections are used to fit the lattice constant of PdTe₂ bulk (Table S1). Among them, the PBE-D2 derived lattice constant (a=4.02 Å, c=5.12 Å) is in excellent agreement with the experiment (a=4.04 Å, c=5.13 Å).⁹ Thus, the PBE-D2 calculations are adopted throughout this work, except for the band gap calculation of PdTe₂ thin films, where the HSE06 hybrid functional is used.¹⁰ The PdTe₂ surfaces are modelled using (2×2) and (4×4) PdTe₂ supercells with the vacuum layer of ~23 Å, and the Brillouin zones are sampled with Γ -centered k-meshes of 6×6×1 and 2×2×1, respectively. The dipole correction is applied to decouple the interaction between periodically repeated images. The geometrical structures are relaxed until the force on each atom is less than 0.05 eV/Å. The transition state is determined using the climbing image nudged elastic band (CI-NEB) and dimer methods with the forces converged to be less than 0.05 eV/Å.¹¹ The spin-polarization has been investigated for the O₂ adsorption in the interfacial model ($O_2^* | H^+ @ WL$), and we find that it has no effect on the system (Table S2). The phonon spectrum is calculated using Phonopy code with finite difference method.¹² Considering the contributions of zero-point energy and entropy, the corrections of 0.05, 0.40, 0.05, and 0.35 eV are made for the calculated

binding energies of O_2^* , OOH^* , O^* , and OH^* , respectively.¹³ The solvation energies are calculated using VASPsol.¹⁴ It is found that O_2^* , OOH^* , O^* , and OH^* are stabilized by -0.07, -0.15, -0.13, and -0.12 eV, respectively.

Oxygen Reduction Reaction

The free energy of coupled proton-electron pair is computed based on the computational hydrogen electrode (CHE) model,¹⁵ which derives $\mu(H^+) + \mu(e^-) = 1/2\mu(H_2) - eU$. The potential U is the electrode potential versus the reversible hydrogen electrode (RHE). The limiting potential is defined as the highest potential at which all the electrochemical steps are downhill in free energies. In this work, we consider the ORR at acid environment with pH=0. The relevant reaction steps are given in equations (1)-(4).



where * denotes the active site on the catalyst. The free energies of O_2 , $*OOH$, $*O$, and $*OH$ at a given potential U relative to RHE are defined as

$$\Delta G(O_2) = 4.92 - 4eU$$

$$\Delta G(OOH^*) = G(OOH^*) + \frac{3G(H_2)}{2} - G(*) - 2G(H_2O) - 3eU$$

$$\Delta G(O^*) = G(O^*) + G(H_2) - G(*) - G(H_2O) - 2eU$$

$$\Delta G(OH^*) = G(OH^*) + \frac{G(H_2)}{2} - G(^*) - G(H_2O) - eU$$

The Capacitor Model

If the interface is close to an ideal capacitor, ΔG_{int} will take the form

$$\Delta G_{int} = \frac{1}{2}C(U - U_{SHE})^2 + \Delta G_0$$

where C refers to the capacitance of the interface, U is the electrode potential, and U_{SHE} is an internal definition of the standard hydrogen electrode potential at which ΔG_{int} reaches the minimum ΔG_0 .

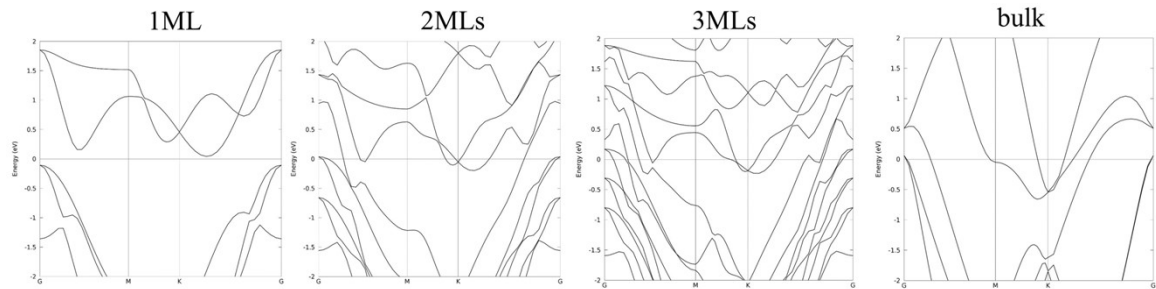


Figure S1. HSE06 calculated band structures of PdTe₂ with 1ML, 2MLs, and 3MLs, and of PdTe₂ bulk.

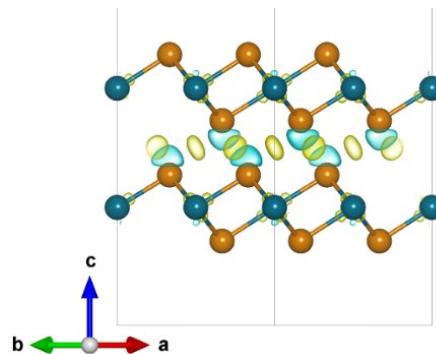


Figure S2. Charge density difference plot with isosurface of $\pm 0.002 \text{ e}/\text{\AA}^3$. Yellow and light green regions represent charge accumulation and depletion, respectively.

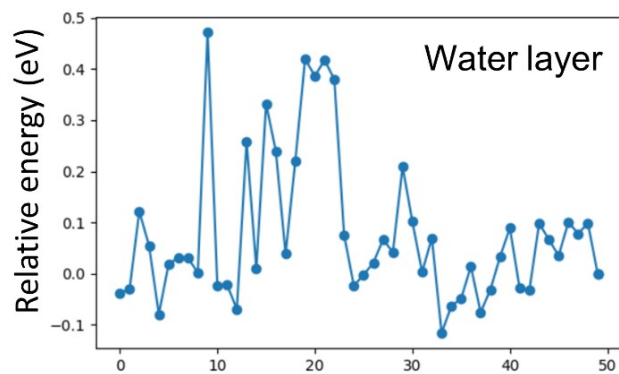


Figure S3. Relative energies of local minima of the water layer on the PdTe₂ bilayer determined by the minima hopping algorithm.

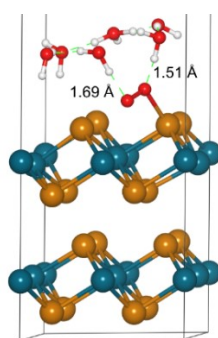


Figure S4. Geometrical configuration of $O_2^*|H^+@WL$. The lengths of hydrogen bonds formed between O_2^* and interfacial H_2O molecules are indicated.

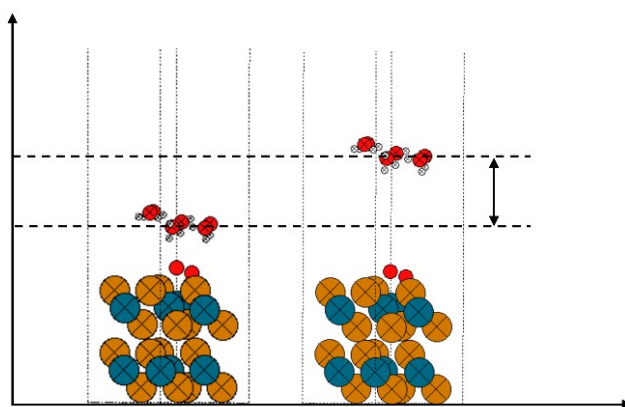


Figure S5. Schematic illustrating the regulation of the vertical height between water layer and the PdTe₂ surface, with the dashed lines representing the upper and lower boundaries of height. At the lower boundary of height, the distance between O_2^* and nearest H_2O molecules is greater than 3 Å, thus avoiding the hydrogen bonding

interaction. The label “x” denotes the fixed atom.

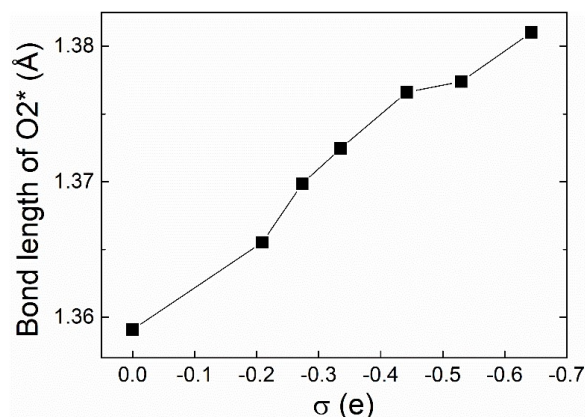


Figure S6. Bond length of O_2^* plotted as a function of the charge on the $PdTe_2$ bilayer.

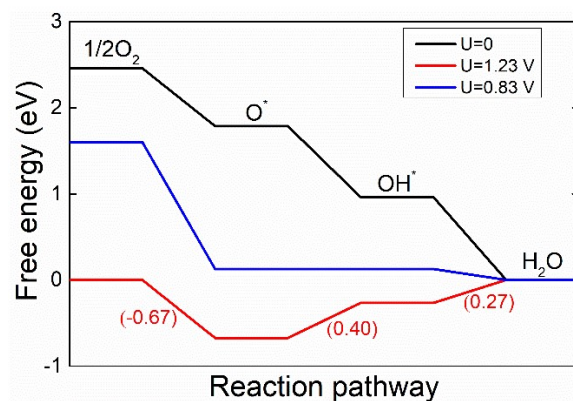


Figure S7. Free energy diagram of ORR on the $PdTe_2$ bilayer determined using the CHE model. The value in the bracket is the reaction free energy in eV at $U=1.23$ V.

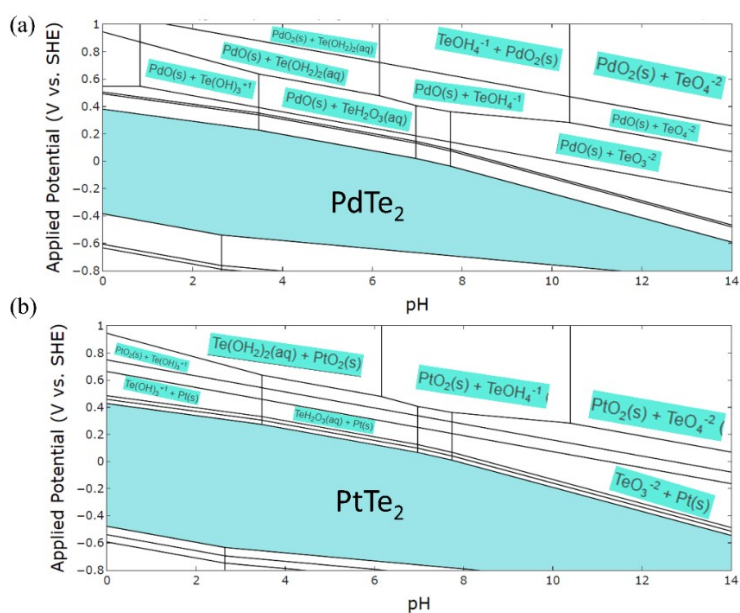


Figure S8. The Pourbaix diagrams of (a) $PdTe_2$ and (b) $PtTe_2$ produced using the DFT database in the Materials Project.¹⁶

Table S1. Calculated lattice constants of the PdTe₂ bulk using different combinations of exchange-correlation functionals and dispersion correction methods.

XC functional	Lattice constant (Å)
PBE	a= 4.10; c= 5.20
PBE-D2	a= 4.02; c= 5.12
PBE-D3 with zero damping	a=4.07; c=5.02
RPBE-D3 with zero damping	a= 4.07; c= 5.05
BEEF-vdW	a=4.13; c=5.28
Exp	a= 4.04; c= 5.13

Table S2. The DFT calculated total energies (eV) of $O_2^*|H^+ @WL$ and $H^+ @WL$ at different sigma values with and without spin-polarization.

Spin-unpolarized	$O_2^* H^+ @WL$	$H^+ @WL$	ΔE_{diff}
Sigma=0.2 eV	-210.207	-199.516	-10.691
Sigma=0.1 eV	-210.200	-199.520	-10.680
Sigma=0.05 eV	-210.197	-199.516	-10.682
Spin-polarized			
Sigma=0.2 eV	-210.207	-199.516	-10.690
Sigma=0.1 eV	-210.200	-199.521	-10.680
Sigma=0.05 eV	-210.197	-199.516	-10.681

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